



MMF150S120DK MMF150S120DK2B

1200V 150A FRED Module
RoHS Compliant

February 2011

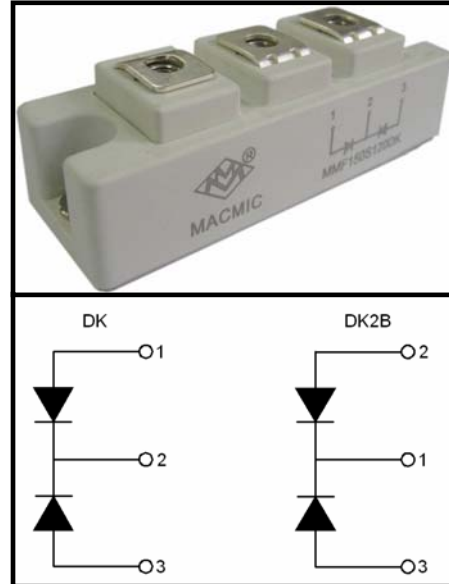
PRELIMINARY

PRODUCT FEATURES

- Ultrafast Reverse Recovery Time
- Soft Reverse Recovery Characteristics
- Low Reverse Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Inductance Package

APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply (UPS)
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- Power Factor Correction (PFC) Circuit



ABSOLUTE MAXIMUM RATINGS

$T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V_R	Maximum D.C. Reverse Voltage		1200	V
V_{RRM}	Maximum Repetitive Reverse Voltage		1200	V
$I_{F(AV)}$	Average Forward Current	$T_C=110^{\circ}\text{C}$, Per Diode	150	A
		$T_C=120^{\circ}\text{C}$, 20KHz, Per Moudle	200	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=110^{\circ}\text{C}$, Per Diode	210	A
I_{FSM}	Non-Repetitive Surge Forward Current	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$, 50Hz, Sine	1500	A
		$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine	1600	A
I^2t	I^2t (For Fusing)	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$, 50Hz, Sine	11200	A^2s
		$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine	12800	A^2s
P_D	Power Dissipation		568	W
T_J	Junction Temperature		-40 to +150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range		-40 to +125	$^{\circ}\text{C}$
V_{isol}	Insulation Test Voltage	AC, $t=1\text{min}$	3000	V
Torque	Module-to-Sink	Recommended (M6)	3~5	N·m
Torque	Module Electrodes	Recommended (M6)	3~5	N·m
$R_{\theta JC}$	Thermal Resistance	Junction-to-Case	0.22	$^{\circ}\text{C}/\text{W}$
Weight			160	g

MacMic Science & Technology Co., Ltd.

Add: #18, Hua Shan Zhong Lu, New District, Changzhou City, Jiangsu Province, P. R .of China

Tel.: +86-519-85163708 Fax: +86-519-85162291 Post Code: 213022 Website: www.macmicst.com

ELECTRICAL CHARACTERISTICS

$T_C=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R=1200\text{V}$	--	--	2	mA
		$V_R=1200\text{V}, T_J=125^\circ\text{C}$	--	--	10	mA
V_F	Forward Voltage	$I_F=150\text{A}$	--	1.6	--	V
		$I_F=150\text{A}, T_J=125^\circ\text{C}$	--	1.3	--	V
t_{rr}	Reverse Recovery Time	$I_F=1\text{A}, V_R=30\text{V}, di_F/dt=-200\text{A}/\mu\text{s}$	--	60	--	ns
t_{rr}	Reverse Recovery Time	$V_R=600\text{V}, I_F=150\text{A}$	--	145	--	ns
I_{RRM}	Max. Reverse Recovery Current		$di_F/dt=-200\text{A}/\mu\text{s}, T_J=25^\circ\text{C}$	--	11	--
t_{rr}	Reverse Recovery Time	$V_R=600\text{V}, I_F=150\text{A}$	--	545	--	ns
I_{RRM}	Max. Reverse Recovery Current		$di_F/dt=-200\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$	--	25	--

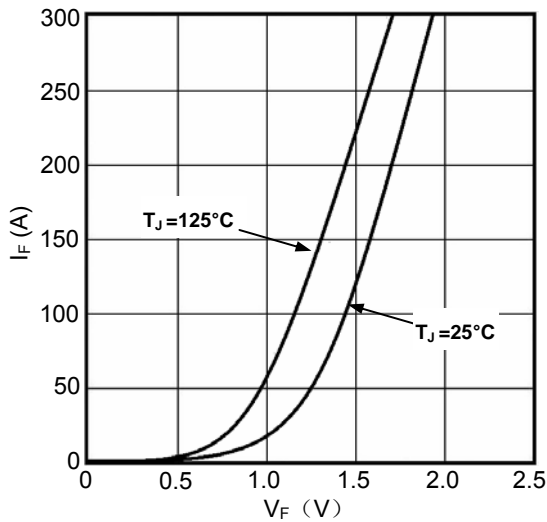


Figure1. Forward Voltage Drop vs Forward Current

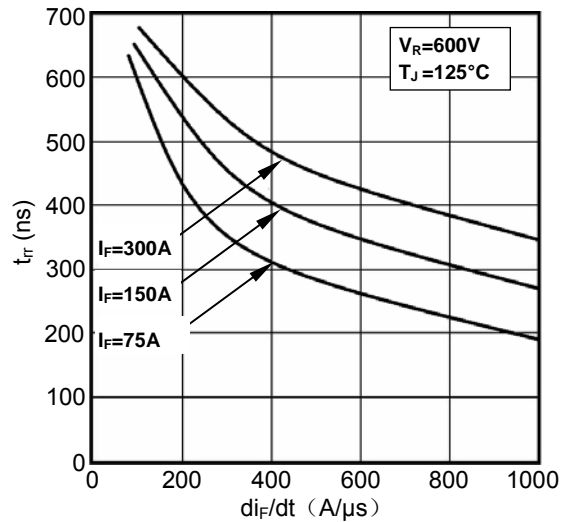


Figure2. Reverse Recovery Time vs di_F/dt

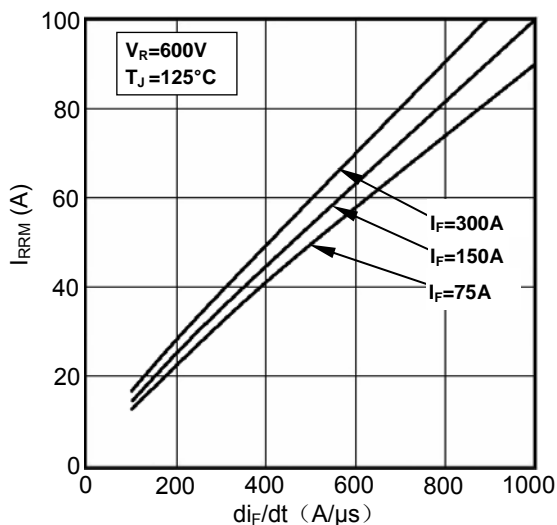


Figure3. Reverse Recovery Current vs di_F/dt

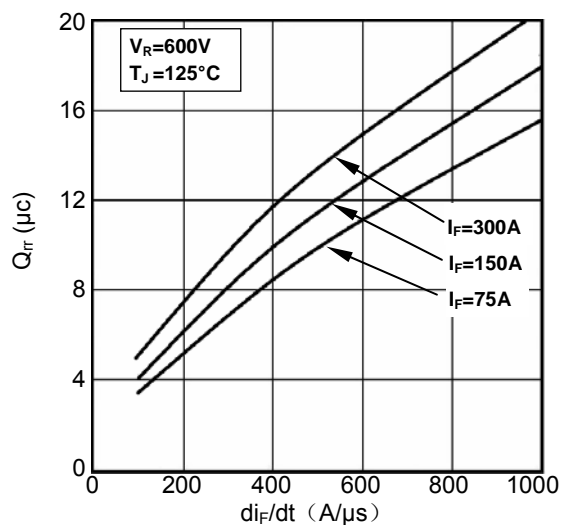


Figure4. Reverse Recovery Charge vs di_F/dt

**MMF150S120DK
MMF150S120DK2B**

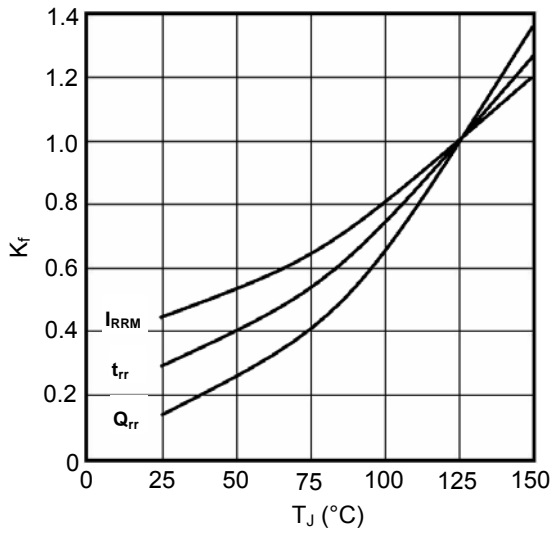


Figure5. Dynamic Parameters vs Junction Temperature

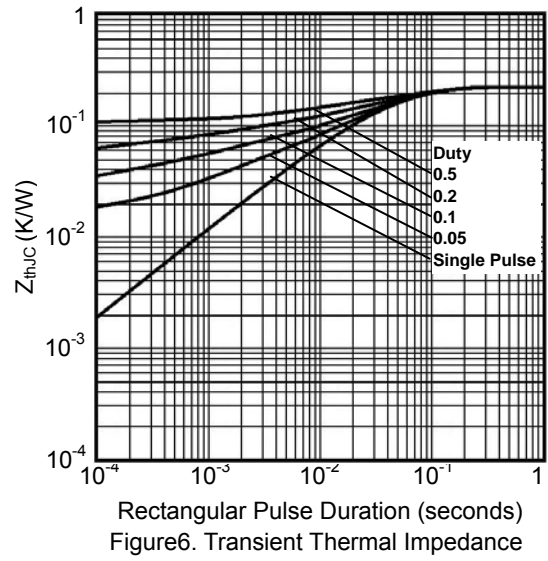
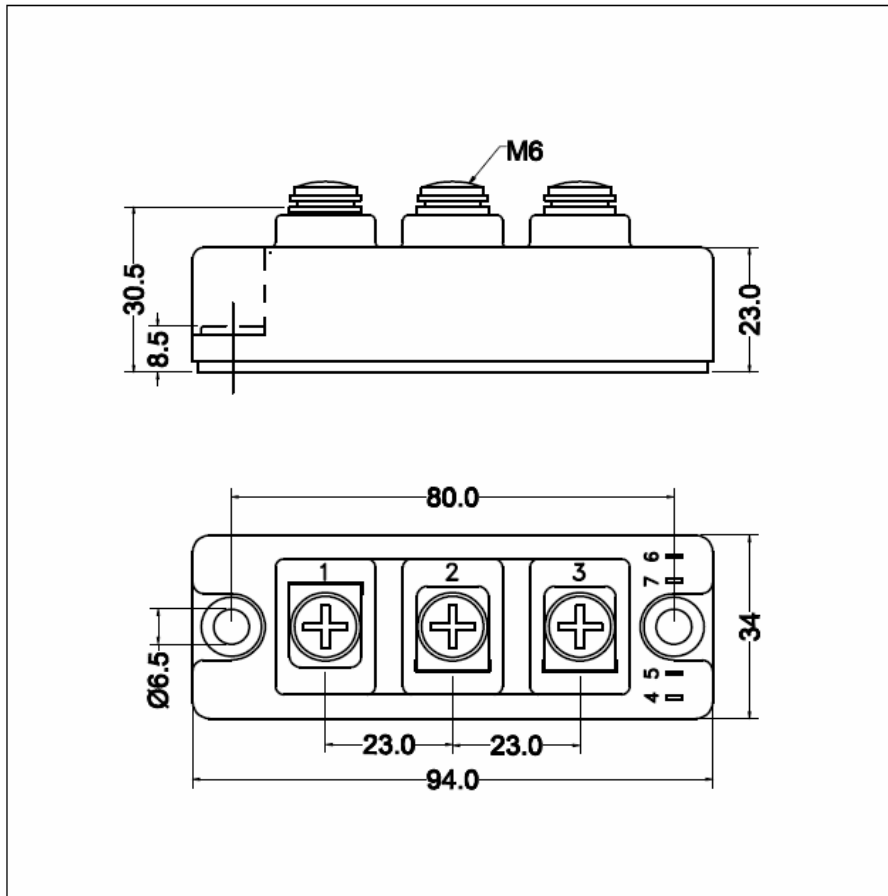


Figure6. Transient Thermal Impedance



Dimensions (mm)
Figure7. Package Outline